Wideband Quad 2:1 Video **Switch**

The NCS6433 is a wide bandwidth, bidirectional, Quad 2:1, NMOS-based video switch suitable for dealing with video signals such as RGB, composite, S-Video, and component video (YPbPr).

The NCS6433 is controlled by a single switch–enabled (\overline{OE}) input. When \overline{OE} is low the switch is enabled and the A port is connected to the B port. When \overline{OE} is high the switch is disabled and the high-impedance state exists between the A and B ports. The line select (SEL) input controls the data path of the multiplexer/demultiplexer.

The NCS6433 has a wide bandwidth, low crosstalk, low on resistance, and fast switching times making it suitable for high-frequency video applications in high definition LCD TV's.

Features

- Very Wide Frequency Bandwidth: 570 MHz
- Low Switch Serial Resistance R_{DS(on)}, 4 Ω Typical
- Power Supply Voltage, 5 V
- Less Than 0.25 ns Bidirectional Maximum Propagation Delay Through Switch
- Low Quiescent Current: 3 μA Maximum
- Very Low Crosstalk, -80 dB Typical at 10 MHz
- Control Inputs are TTL/CMOS Compatible
- Ideal for High Definition Video Applications
- ESD HBM Protection 8 kV
- Fast Switching Better Than 10 ns
- Capable of Driving a High Current at the Output (>100 mA)
- Available in SOIC-16 or TSSOP-16 Package
- This is a Pb-Free Device

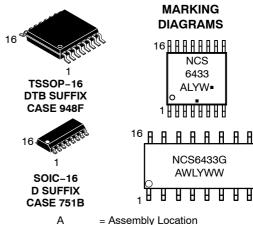
Typical Applications

- Flat Panel Displays including LCDTV
- CRT Displays
- DVD Reader/Writer
- Set-Top Boxes



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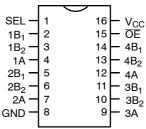


= Wafer Lot WL, L Υ = Year

WW. W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



TRUTH TABLE

SEL	ŌĒ	Function
X	H	Open
L	L	A = B ₁
H	L	A = B ₂

PIN NAMES

1

Pin	Description
ŌĒ	Bus Switch Enables
SEL	Select Inputs
A	Bus A
B ₁ , B ₂	Bus B

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

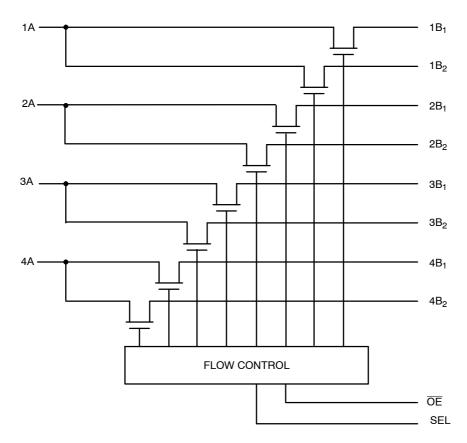


Figure 1. NCS6433 Block Diagram

ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
NCS6433DR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NCS6433DTBR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ATTRIBUTES

Characteristics		Value
ESD Protection Human Body Model, R = 1000 Ω , C = 100 pl (Note 1) Machine Model	F I/O Pins 2–7, 9–14 All Pins All Pins	8 kV 2 kV 100 V
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in.
Meets or exceeds JEDEC Spec EIA/JESD78	B IC Latch-up Test	

- 1. Meets or exceeds JEDEC spec JESD22-A114-B.
- 2. For additional information, see Application Note AND8003/D

MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
DC Supply Voltage		V _{CC}	-0.5 to +5.5	V
DC Input Voltage		VI	-0.5 to +5.5	V
DC Output Voltage		Vo	-0.5 to +5.5	V
DC Input Diode Current		I _{IK}	-50	mA
DC Output Diode Current		I _{OK}	-50	mA
DC Output Sink Current		I _O	128	mA
DC Supply Current per Supply Pin		I _{CC}	±100	mA
DC Ground Current per Ground Pin		I_{GND}	±100	mA
Storage Temperature Range		T _{STG}	−65 to +150	°C
Lead Temperature, 1 mm from Case for 10 Seconds		TL	260	°C
Junction Temperature Under Bias (Note 3)		T_J	+150	°C
Thermal Resistance	SOIC-16 TSSOP-16	$\theta_{\sf JA}$	125 170	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Symbol	Par	ameter	Min	Max	Unit
V _{CC}	Supply Voltage	Operating, Data Retention Only	4.75	5.25	V
VI	Input Voltage	(Note 4)	0	5.25	V
Vo	Output Voltage	(HIGH or LOW State)	0	5.25	V
T _A	Operating Free-Air Temperature		-40	+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate Switch I/O	Switch Control Input V_{CC} = 5.0 V \pm 0.5 V	0	DC 5	ns/V

^{4.} Unused control inputs may not be left open. All control inputs must be tied to a high or low logic input voltage level.

^{3.} Maximum electrical ratings are defined as those values beyond which damage to the device may occur at $T_A = +25$ °C.

DC ELECTRICAL CHARACTERISTICS ($T_A = -40^{\circ}C$ to $+85^{\circ}C$ for Min and Max values, $T_A = 25^{\circ}C$ for Typ values)

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Тур*	Max	Unit
V _{IK}	Clamp Diode Voltage	I _{IN} = -18 mA	4.5	-1.2	-0.8		V
V _{IH}	High-Level Input Voltage		4.0 to 5.5	2.0			V
V _{IL}	Low-Level Input Voltage		4.0 to 5.5			0.8	V
ILI	Input Leakage Current	$0 \le V_{IN} \le 5.5 \text{ V}$	5.5			±1.0	μΑ
l _{OZ}	Off-State Leakage Current	$0 \le A, B \le V_{CC}$	5.5			±1.0	μΑ
R _{ON}	Switch On Resistance (Note 5)	V_{IN} = 1 V, I_{ON} = 13 mA, R_L = 75 Ω	4.5		4.0	7.0	Ω
		V_{IN} = 2 V, I_{ON} = 26 mA, R_L = 75 Ω	4.5		7.0	10	
I _{CC}	Quiescent Supply Current	V _{IN} = V _{CC} or GND, I _{OUT} = 0	5.5			3.0	μΑ
Δl _{CC}	Increase In I _{CC} per Input	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5			2.5	mA

AC ELECTRICAL CHARACTERISTICS ($T_A = -40$ °C to +85 °C, $C_L = 20$ pF, RU = RD = 75 Ω unless otherwise specified) (Note 6)

			V _C	_C = 4.5–5.5	5 V	
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{ON}	Turn On Time	R_L = 75 Ω , C_L = 20 pF, see Figure 7		2.8	5.0	ns
t _{OFF}	Turn Off Time	R_L = 75 Ω , C_L = 20 pF, see Figure 7		1.4	5.0	ns
BW	−3 dB Bandwidth	R _L = 150 Ω, T _A = 25°C			570	MHz
X _{talk}	Crosstalk Adjacent Non-Adjacent	10 MHz, $C_L = 0$ pF, $R_L = 150 \Omega$		-47 -80		dB
Off _{ISO}	Off Isolation	10 MHz, C_L = 0 pF, R_L = 150 Ω		-48		dB

^{6.} $T_A = +25^{\circ}C$, parameters characterized but not tested.

CAPACITANCES (Note 7)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{IN}	Control Pin Input Capacitance	V _{CC} = 5.0 V		2.0		pF
C _{I/OA}	A Port Input/Output Capacitance	$V_{CC} = \overline{OE} = 5.0 \text{ V}$		5.0		pF
C _{I/OB}	B Port Input/Output Capacitance	$V_{CC} = \overline{OE} = 5.0 \text{ V}$		5.0		pF

^{7.} $T_A = +25^{\circ}C$, f = 1 MHz, Capacitance is characterized but not tested.

^{*}Typical values are at V_{CC} = 5.0 V and T_A = 25°C.

5. Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

TYPICAL CHARACTERISTICS

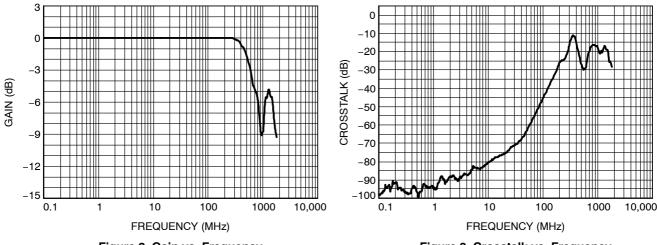


Figure 2. Gain vs. Frequency

Figure 3. Crosstalk vs. Frequency (Non-Adjacent Channels)

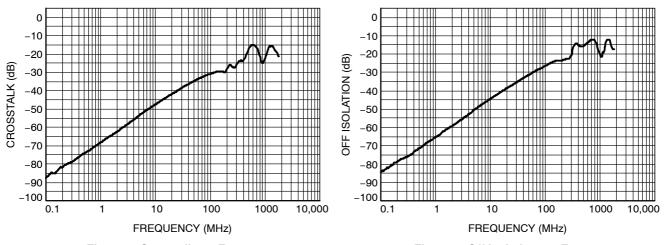


Figure 4. Crosstalk vs. Frequency (Adjacent Channels)

Figure 5. Off Isolation vs. Frequency

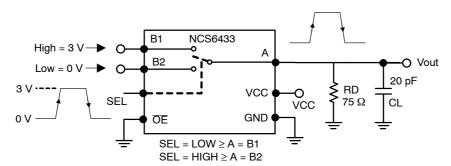


Figure 6. AC Test Circuit for Turn-on and Turn-off Times

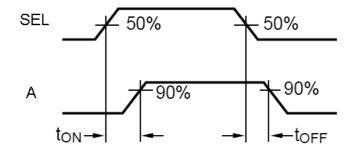


Figure 7. Turn-on and Turn-off Times

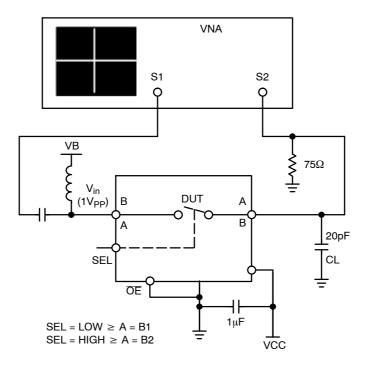


Figure 8. Gain, Crosstalk, Off-Isolation

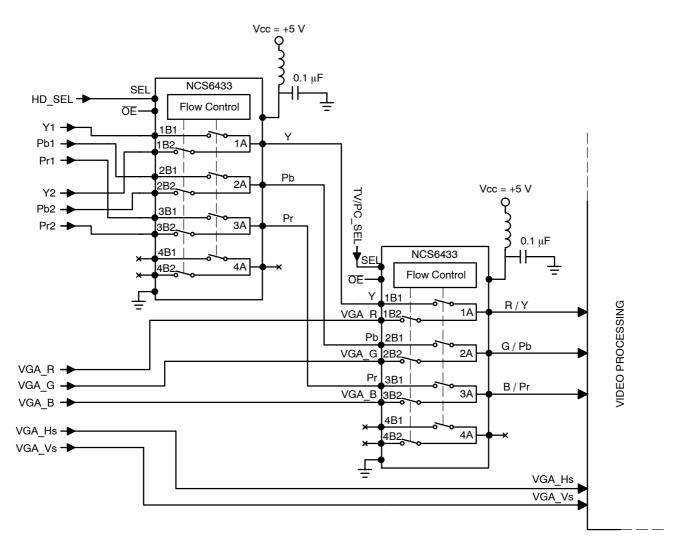


Figure 9. Example of LCDTV Application Using the Video Switch NCS6433



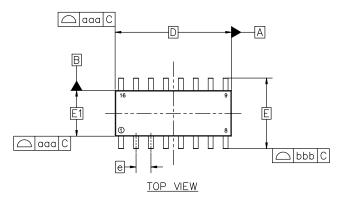


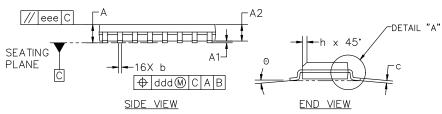
SOIC-16 9.90x3.90x1.50 1.27P CASE 751B ISSUE L

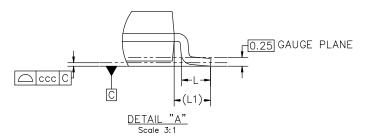
DATE 29 MAY 2024

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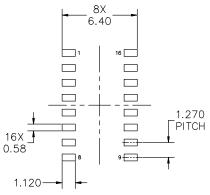
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
- 3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE 6 DIMENSION AT MAXIMUM MATERIAL CONDITION.







	MILLIMETERS					
DIM	MIN	NOM	MAX			
А	1.35	1.55	1.75			
A1	0.00	0.05	0.10			
A2	1.35	1.50	1.65			
b	0.35	0.42	0.49			
С	0.19	0.22	0.25			
D	9.90 BSC					
E	6.00 BSC					
E1	3.90 BSC					
е		1.27 BSC				
h	0.25		0.50			
L	0.40	0.83	1.25			
L1		1.05 REF				
Θ	0.		7°			
TOLERAN	CE OF FC	RM AND	POSITION			
aaa		0.10				
bbb		0.20				
ccc		0.10				
ddd		0.25				
eee		0.10				



RECOMMENDED MOUNTING FOOTPRINT

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PLEASE DOWNLOAD THE onsemi SOLDERING
AND MOUNTING TECHNIQUES REFERENCE
MANUAL, SOLDERRM/D

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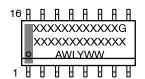
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SOIC-16 9.90x3.90x1.50 1.27P CASE 751B ISSUE L

DATE 29 MAY 2024

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code

A = Assembly Location

WL = Wafer Lot
 Y = Year
 WW = Work Week
 G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

077/15/		077/15.0		071/15 0		T	
STYLE 1: PIN 1.	COLLECTOR	STYLE 2:	CATHODE	STYLE 3: PIN 1.		TYLE 4: PIN 1.	COLLECTOR DVF #1
PIN 1. 2.		PIN 1. 2.		PIN 1. 2.	COLLECTOR, DYE #1 BASE, #1	2.	
2. 3.	EMITTER	2. 3.	NO CONNECTION				
				3.		3.	
4.	NO CONNECTION	4.		4.		4.	
5.	EMITTER	5.		5.		5.	
6.	BASE	6.		6.		6.	
7.		7.			EMITTER, #2		COLLECTOR, #4
8.		8.		8.			COLLECTOR, #4
9.		9.			COLLECTOR, #3		BASE, #4
10.			ANODE		BASE, #3		EMITTER, #4
	NO CONNECTION	11.			EMITTER, #3		BASE, #3
	EMITTER		CATHODE		COLLECTOR, #3		EMITTER, #3
	BASE		CATHODE		COLLECTOR, #4		BASE, #2
	COLLECTOR	14.			BASE, #4		EMITTER, #2
15.			ANODE		EMITTER, #4		BASE, #1
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1
STYLE 5:		STYLE 6:		STYLE 7:			
STYLE 5: PIN 1.	DRAIN, DYE #1	STYLE 6: PIN 1.	CATHODE	STYLE 7: PIN 1.	SOURCE N-CH		
	DRAIN, DYE #1 DRAIN, #1			PIN 1.	SOURCE N-CH COMMON DRAIN (OUTPUT)		
PIN 1.	,	PIN 1.	CATHODE	PIN 1.	COMMON DRAIN (OUTPUT)		
PIN 1. 2.	DRAIN, #1	PIN 1. 2.	CATHODE CATHODE	PIN 1. 2.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3.	DRAIN, #1 DRAIN, #2	PIN 1. 2. 3.	CATHODE CATHODE	PIN 1. 2. 3.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4.	DRAIN, #1 DRAIN, #2 DRAIN, #2	PIN 1. 2. 3. 4.	CATHODE CATHODE CATHODE CATHODE	PIN 1. 2. 3. 4.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4. 5.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3	PIN 1. 2. 3. 4. 5.	CATHODE CATHODE CATHODE CATHODE	PIN 1. 2. 3. 4. 5.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4. 5.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4	PIN 1. 2. 3. 4. 5.	CATHODE CATHODE CATHODE CATHODE CATHODE	PIN 1. 2. 3. 4. 5.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4. 5. 6. 7.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3	PIN 1. 2. 3. 4. 5. 6.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE	PIN 1. 2. 3. 4. 5. 6.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH		
PIN 1. 2. 3. 4. 5. 6. 7.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4	PIN 1. 2. 3. 4. 5. 6. 7.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH		
PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4 SOURCE, #4	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4 GATE, #4 SOURCE, #4 GATE, #3	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4 SOURCE, #4	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE ANODE ANODE ANODE ANODE ANODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 GATE, #4 SOURCE, #4 GATE, #3 SOURCE, #3 GATE, #2	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE ANODE ANODE ANODE ANODE ANODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GOMMON DRAIN (OUTPUT) GATE N-CH		
PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4 DRAIN, #4 GATE, #4 SOURCE, #4 GATE, #3 SOURCE, #3 GATE, #2 SOURCE, #2 SOURCE, #2	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) CATE N-CH COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 GATE, #4 SOURCE, #4 GATE, #3 SOURCE, #3 GATE, #2	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE N-CH COMMON DRAIN (OUTPUT)		

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2X L/2

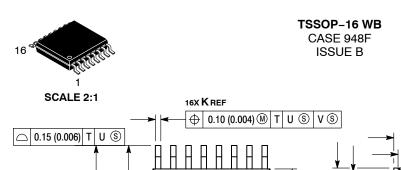
L

☐ 0.15 (0.006)

PIN 1 IDENT.

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DATE 19 OCT 2006

NOTES

Κ

SECTION N-N

0.25 (0.010)

J1

В

-U-

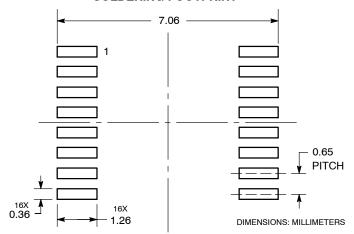
- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT
- EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
 INTERLEAD FLASH OR PROTRUSION.
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
 NOT EXCEED 0.25 (0.010) PER SIDE.
 DIMENSION K DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABILE DAMBAR
 PROTRUSION SHALL BE 0.08 (0.003) TOTAL
 IN EXCESS OF THE K DIMENSION AT
 MAXIMUM MATERIAL CONDITION.
 TERMINIAL NILMBERS ADE SUCIUMI ECIP.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.18	0.28	0.007	0.011
7	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	00	00	00	0 0

DETAIL E -W-☐ 0.10 (0.004) **DETAIL E** SEATING PLANE D

RECOMMENDED SOLDERING FOOTPRINT*

-V-



^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



= Specific Device Code XXXX Α = Assembly Location

= Wafer Lot L = Year W = Work Week G or • = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	TSSOP-16		PAGE 1 OF 1	

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